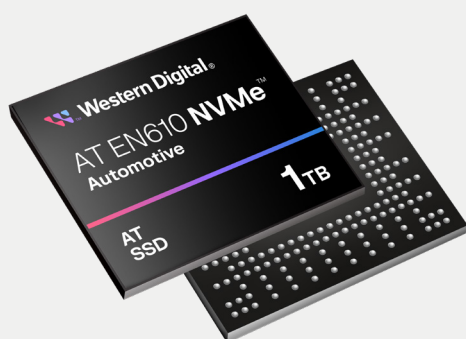




PRODUCT BRIEF



Product Highlights

- High performance at Automotive - temperatures -40°C to +105°C³
- SR-IOV with 8 x Virtual Functions
- PCIe Gen4x4
- M.2 Type 1620 BGA
- 256GB, 512GB, 1TB¹
- 32 namespaces TLC and SLC configurable

Applications

- High Performance Central Compute
- In-Vehicle Infotainment (IVI)
- Advanced Driver Assist Systems (ADAS)
- Autonomous Driving System (ADS)
- Multi-host needing shared storage

Western Digital® AT EN610 NVMe™ SSD

Supporting the distributed and shared architectures

Western Digital AT EN610 NVMe SSD offers an automotive-grade, high-performance, wide-temperature range storage solution designed for the demanding requirements of next-generation automotive architectures. With flexibility through high-capacity TLC and high-endurance SLC options, the AT EN610 offers an M.2 Type 1620 BGA form factor and up to 1TB of storage space.

Flexibility for distinct needs

Up to four PCIe® Gen4 lanes deliver exceptional speed and offer a versatile storage solution, with up to 1TB¹ of TLC storage. This can be fully or partially configured to SLC storage for applications requiring lower latencies, higher endurance, and higher write sustained performance.

Virtualization enablement

SR-IOV technology enables multiple Virtual Functions (VFs) within a single SSD, resulting in each application having its own virtual SSD.

Automotive-grade design

AT EN610 NVMe SSD complies with AEC-Q100, ISO 26262, and ASPICE, and goes through rigorous testing to ensure the reliability and quality essential for automotive applications. This device is outfitted in a BGA 16mm x 20mm package with a pin-out adhering to PCI-SIG standard specifications, providing a standardized, durable, and solid solution.

Enhanced device security

The device incorporates the TCG Opal 2.02 protocol and utilizes the AES-256-XTS encryption algorithm to ensure that data stored on the drive is encrypted and protected. To further enhanced data security, the secure boot and firmware upgrade processes guarantee that only authorized firmware is executed on the device.

Western Digital AT EN610 NVMe™ SSD

Product specifications						
Form-factor	M.2 Type 1620-S5 BGA per PCI-SIG 16mm x 20mm x 1.8mm (WxHxL)					
Interface	PCIe Gen4x4 (Backward compatible) NVMe 1.4c 1 x Physical Function					
NAND	BiCS5 112L, 512Gb, TLC, auto-trim					
DRAM	DRAMless Host Memory Buffer supported					
Capacities¹	TLC			SLC⁵		
	256GB	512GB	1024GB	85GB	170GB	340GB
Endurance (TBW)	700	1,400	2,800	7,500	15,000	30,000
Performance²						
Burst Sequential Read [MB/s]	2,500	3,700	3,700	2,500	3,700	3,700
Burst Sequential Write [MB/s]	1,100	2,200	3,000	1,100	2,200	3,000
Sustained Sequential Read [MB/s]	1,900	3,000	3,500	2,500	3,300	3,700
Sustained Sequential Write [MB/s]	200	400	800	1,100	2,200	3,000
Random Read [IOPs]	120K	200K	270K	190K	290K	330K
Random Write [IOPs]	55K	110K	210K	230K	320K	430K
Temperatures⁵	-40°C to +105°C, AEC-Q100 Grade-2					
Power⁶	6.8W (peak), 5.0W (avg @ 2.5V PS0), 5mW (lowest power state PS0/D3)					
Power Supply	PWR_1: 3.3V/2.5V PWR_2: 1.2V PWR_3: 0.8V					
Virtualization	SR-IOV with 8 x Virtual Functions Virtualization Management					
Namespaces	32 Namespaces Each can be configured as TLC and SLC up to the available LBA range Capabilities: Namespace Format, Namespace Reservations, and control access					
Health Reporting	Enhanced Automotive Self-Monitoring Advanced Reporting Technology (S.M.A.R.T.), in addition to NVMe standard-defined SMART attributes					
Data Integrity	Low-density parity-check code (LDPC) Page-level protection with XOR mechanism End-to-End Data-Path Protection (E2E DPP) SRAM Error-Code Correction					
Reliability	Automatic Data Self-refresh and Host Manual Refresh Comprehensive thermal management with full performance up to above +105°C					
Security	TCG Opal 2.02 support, Secure boot, Secure FFU and locking external connections					
Safety	ISO-26262 ASIL-B ready, Safety Manual and FMEDA report availability					
Automotive Compliant	A-SPICE level-2 and IATF16949 Certification AEC-Q100, APQP and PPAP and ZVEI PCN					
Order Information						
	256GB	512GB	1024GB			
	SDDQUGD-256G-ZA	SDDQUGD-512G-ZA	SDDQUGD-1T00-ZA			

1. Per IDEMA specifications. One gigabyte (GB) is equal to one billion bytes and one terabyte (TB) is equal to one trillion byte. Actual user capacity may be less due to operating environment.

2. HMB enabled. All numbers are measured under nominal voltage and room temperature. One megabyte (MB) is equal to one million bytes. Precondition: filling the drive twice sequential data. Sequential test settings: QD=8 | Threads=1 | Range size=1GB | Block size=128KB; Sequential sustained test settings: QD=8 | Threads=1 | Range size=100% | Block size=128KB. Random test setting: QD=32 | Threads=16 | Range size=1GB | Block size=4KB

3. Operational temperature is defined as -40°C refers to ambient temperature. +105°C refers to the SMART composite temperature reported by the drive. (when thermal throttling is triggered)

4. Typical Power Number under nominal conditions and subject to change.

5. If configured as 100% SLC

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